



8013-1006  
PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Masaru KURAMOTO et al.

Confirmation No. 9452

Serial No. 10/091,437

Group 2811

Filed March 7, 2002

GROUP III-V COMPOUND SEMICONDUCTOR CRYSTAL STRUCTURE AND  
METHOD OF EPITXIAL GROWTH OF THE SAME AS WELL AS SEMICONDUCTOR  
DEVICE INCLUDING THE SAME

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents  
Washington, D.C. 20231

Sir:

In compliance with Rules 1.97 and 1.98, and in fulfillment of the duty of disclosure under Rule 1.56, the accompanying documents, copies of which are attached to this statement, are made of record on the enclosed sheet.

A concise explanation of the relevance of these items is that these references were cited by the Taiwanese Patent Office in the corresponding Taiwanese Application. A copy of the Taiwanese Official Action in which they were cited is attached hereto, with an English translation.

Respectfully submitted,

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By

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